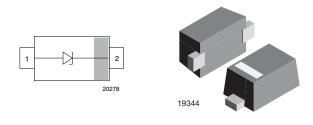


Vishay Semiconductors

Single ESD-Protection Diode in SOD-523



FEATURES

- Single-line ESD-protection
- Low leakage current
- ESD-immunity acc. IEC 61000-4-2 ± 8 kV contact discharge ± 15 kV air discharge
- e3 Sn
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC





MARKING (example only)



Bar = cathode marking

X = date code

Y = type code (see table below)

in accordance to WEEE 2002/96/EC	

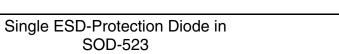
ORDERING INFORMATION					
DEVICE NAME	ORDERING CODE	TAPED UNITS PER REEL (8 mm TAPE ON 7" REEL)	MINIMUM ORDER QUANTITY		
VESD01-02V	VESD01-02V-G-08	3000	3000		
VESD03-02V	VESD03-02V-G-08	3000	3000		
VESD05-02V	VESD05-02V-G-08	3000	3000		
VESD08-02V	VESD08-02V-G-08	3000	3000		
VESD12-02V	VESD12-02V-G-08	3000	3000		

PACKAGE DATA						
DEVICE NAME	PACKAGE NAME	TYPE CODE	WEIGHT	MOLDING COMPOUND FLAMMABILITY RATING	MOISTURE SENSITIVITY LEVEL	SOLDERING CONDITIONS
VESD01-02V	SOD-523	.∀	1.4 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals
VESD03-02V	SOD-523	. В	1.4 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals
VESD05-02V	SOD-523	.o	1.4 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals
VESD08-02V	SOD-523	.a	1.4 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals
VESD12-02V	SOD-523	. 3	1.4 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals

** Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902

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ABSOLUTE MAXIMUM RATINGS VESD01-02V					
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT	
Peak pulse current	acc. IEC 61000-4-5, 8/20 µs/single shot	I _{PPM}	7	А	
Peak pulse power	acc. IEC 61000-4-5, 8/20 µs/single shot	P _{PP}	63	W	
	Contact discharge acc. IEC 61000-4-2; 10 pulses	M	± 8	kV	
ESD immunity	Air discharge acc. IEC 61000-4-2; 10 pulses	V _{ESD}	± 15	kV	
Operating temperature	Junction temperature	TJ	- 40 to + 125	°C	
Storage temperature		T _{stg}	- 55 to + 150	°C	

ABSOLUTE MAXIMUM RATINGS VESD03-02V					
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT	
Peak pulse current	acc. IEC 61000-4-5, 8/20 µs/single shot	I _{PPM}	9	А	
Peak pulse power	acc. IEC 61000-4-5, 8/20 µs/single shot	P _{PP}	108	W	
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	M	± 8	kV	
ESD minutity	Air discharge acc. IEC 61000-4-2; 10 pulses	V _{ESD}	± 15	kV	
Operating temperature	Junction temperature	TJ	- 40 to + 125	°C	
Storage temperature		T _{stg}	- 55 to + 150	°C	

ABSOLUTE MAXIMUM RATINGS VESD05-02V					
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT	
Peak pulse current	acc. IEC 61000-4-5, 8/20 µs/single shot	I _{PPM}	6	А	
Peak pulse power	acc. IEC 61000-4-5, 8/20 µs/single shot	P _{PP}	120	W	
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V	± 8	kV	
	Air discharge acc. IEC 61000-4-2; 10 pulses	V _{ESD}	± 15	kV	
Operating temperature	Junction temperature	TJ	- 40 to + 125	°C	
Storage temperature		T _{stg}	- 55 to + 150	°C	

ABSOLUTE MAXIMUM RATINGS VESD08-02V					
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT	
Peak pulse current	acc. IEC 61000-4-5, 8/20 µs/single shot	I _{PPM}	4	А	
Peak pulse power	acc. IEC 61000-4-5, 8/20 µs/single shot	P _{PP}	120	W	
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V	± 8	kV	
ESD minumity	Air discharge acc. IEC 61000-4-2; 10 pulses	V _{ESD}	± 15	kV	
Operating temperature	Junction temperature	TJ	- 40 to + 125	°C	
Storage temperature		T _{stg}	- 55 to + 150	°C	

ABSOLUTE MAXIMUM RATINGS VESD12-02V					
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT	
Peak pulse current	acc. IEC 61000-4-5, 8/20 µs/single shot	I _{PPM}	2	А	
Peak pulse power	acc. IEC 61000-4-5, 8/20 µs/single shot	P _{PP}	25	W	
	Contact discharge acc. IEC 61000-4-2; 10 pulses	V	± 8	kV	
ESD immunity	Air discharge acc. IEC 61000-4-2; 10 pulses	V _{ESD}	± 15	kV	
Operating temperature	Junction temperature	TJ	- 40 to + 125	°C	
Storage temperature		T _{stg}	- 55 to + 150	°C	



Single ESD-Protection Diode in SOD-523

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ELECTRICAL CHARACTERISTICS VESD01-02V						
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	N _{channel}	-	-	1	lines
Reverse working voltage	at I _{Rmax.}	V _{RWM}	1	-	-	V
Reverse current	at V _{RWM}	I _R	-	-	100	μA
Reverse breakdown voltage	at I _R = 1 mA	V _{BR}	1.5	-	-	V
Reverse clamping voltage	at I _{PP} (see fig. 1)	V _C	-	9	-	V
Capacitance	at $V_R = 0 V$; f = 1 MHz	CD	-	180	-	pF

ELECTRICAL CHARACTERISTICS VESD03-02V						
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	N _{channel}	-	-	1	lines
Reverse working voltage	at I _{Rmax.}	V _{RWM}	3	-	-	V
Reverse current	at V _{RWM}	I _R	-	-	20	μA
Reverse breakdown voltage	at I _R = 1 mA	V _{BR}	4	-	-	V
Reverse clamping voltage	at I _{PP} (see fig. 1)	V _C	-	12	-	V
Capacitance	at $V_R = 0 V$; f = 1 MHz	CD	-	110	-	pF

ELECTRICAL CHARACTERISTICS VESD05-02V						
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	N _{channel}	-	-	1	lines
Reverse working voltage	at I _{Rmax.}	V _{RWM}	5	-	-	V
Reverse current	at V _{RWM}	I _R	-	-	0.1	μA
Reverse breakdown voltage	at I _R = 1 mA	V _{BR}	6.5	-	-	V
Reverse clamping voltage	at I _{PP} (see fig. 1)	V _C	-	20	-	V
Capacitance	at $V_R = 0 V$; f = 1 MHz	CD	-	55	-	pF

ELECTRICAL CHARACTERISTICS VESD08-02V						
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	N _{channel}	-	-	1	lines
Reverse working voltage	at I _{Rmax.}	V _{RWM}	8	-	-	V
Reverse current	at V _{RWM}	I _R	-	-	0.1	μA
Reverse breakdown voltage	at I _R = 1 mA	V _{BR}	9	-	-	V
Reverse clamping voltage	at I _{PP} (see fig. 1)	V _C	-	30	-	V
Capacitance	at $V_R = 0 V$; f = 1 MHz	CD	-	35	-	pF

ELECTRICAL CHARACTERISTICS VESD12-02V						
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	N _{channel}	-	-	1	lines
Reverse working voltage	at I _{Rmax.}	V _{RWM}	12	-	-	V
Reverse current	at V _{RWM}	I _R	-	-	0.1	μA
Reverse breakdown voltage	at I _R = 1 mA	V _{BR}	14	-	-	V
Reverse clamping voltage	at I _{PP} (see fig. 1)	V _C	-	25	-	V
Capacitance	at $V_R = 0 V$; f = 1 MHz	CD	-	30	-	pF

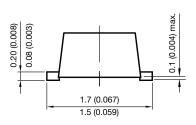
VESDxx-02V

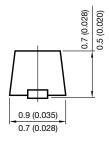
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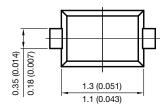
Single ESD-Protection Diode in SOD-523



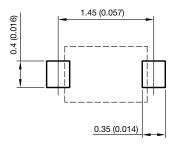
PACKAGE DIMENSIONS in millimeters (inches): SOD-523











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Document Number: 83367 Rev. 1.0, 08-Nov-10



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